

WEST[Help](#)[Logout](#)[Interrupt](#)[Main Menu](#)[Search Form](#)[Posting Counts](#)[Show S Numbers](#)[Edit S Numbers](#)[Preferences](#)[Cases](#)**Search Results -**

Terms	Documents
L8 and semiconductor	2

Database:

US Patents Full-Text Database	▲
US Pre-Grant Publication Full-Text Database	
JPO Abstracts Database	
EPO Abstracts Database	
Derwent World Patents Index	
IBM Technical Disclosure Bulletins	▼

Search:

L13

[Refine Search](#)[Recall Text](#)[Clear](#)**Search History****DATE:** Friday, May 31, 2002 [Printable Copy](#) [Create Case](#)

Set Name Query

side by side

Hit Count Set Name

result set

*DB=DWPI; PLUR=YES; OP=ADJ*L1 (gallium or Ga) adj (N or nitride) and (dop\$ same (Mg or magnesium))58 L1*DB=TDBD; PLUR=YES; OP=ADJ*L2 (gallium or Ga) adj (N or nitride) and (dop\$ same (Mg or magnesium))0 L2*DB=USPT; PLUR=YES; OP=ADJ*L3 (gallium or Ga) adj (N or nitride) and (dop\$ same (Mg or magnesium))335 L3L4 (gallium or Ga) adj (N or nitride) same (dop\$ same (Mg or magnesium))129 L4*DB=DWPI; PLUR=YES; OP=ADJ*L5 (gallium or Ga) adj (N or nitride) same (dop\$ same (Mg or magnesium))40 L5*DB=PGPB; PLUR=YES; OP=ADJ*L6 (gallium or Ga) adj (N or nitride) same (dop\$ same (Mg or magnesium))35 L6*DB=JPAB; PLUR=YES; OP=ADJ*L7 (gallium or Ga) adj (N or nitride) same (dop\$ same (Mg or magnesium))40 L7*DB=EPAB; PLUR=YES; OP=ADJ*L8 (gallium or Ga) adj (N or nitride) same (dop\$ same (Mg or magnesium))5 L8*DB=USPT; PLUR=YES; OP=ADJ*L9 L4 and semiconductor126 L9*DB=DWPI; PLUR=YES; OP=ADJ*L10 L5 and semiconductor30 L10*DB=PGPB; PLUR=YES; OP=ADJ*L11 L6 and semiconductor35 L11*DB=JPAB; PLUR=YES; OP=ADJ*L12 L7 and semiconductor36 L12*DB=EPAB; PLUR=YES; OP=ADJ*L13 L8 and semiconductor2 L13

END OF SEARCH HISTORY